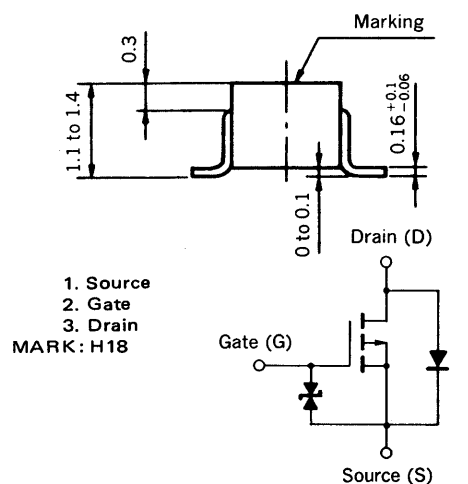


P-CHANNEL MOS FET FOR SWITCHING

Technical drawing of a three-roller assembly. The drawing shows three rollers, labeled 1, 2, and 3, arranged horizontally. Roller 1 is on the left, roller 2 is in the middle, and roller 3 is on the right. The total width of the assembly is 2.9 ± 0.2 . The distance between the centerlines of rollers 1 and 2 is 0.95 . The distance between the centerlines of rollers 2 and 3 is 0.4 ± 0.1 . The distance from the centerline of roller 2 to the right edge of roller 3 is 0.65 ± 0.1 . The distance from the centerline of roller 2 to the right edge of roller 1 is 2.8 ± 0.2 . The distance from the centerline of roller 2 to the right edge of roller 2 is 1.5 . The drawing also shows the centerlines of the rollers and the edges of the rollers.

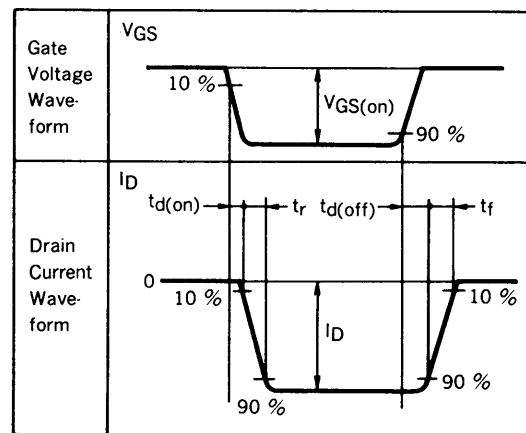
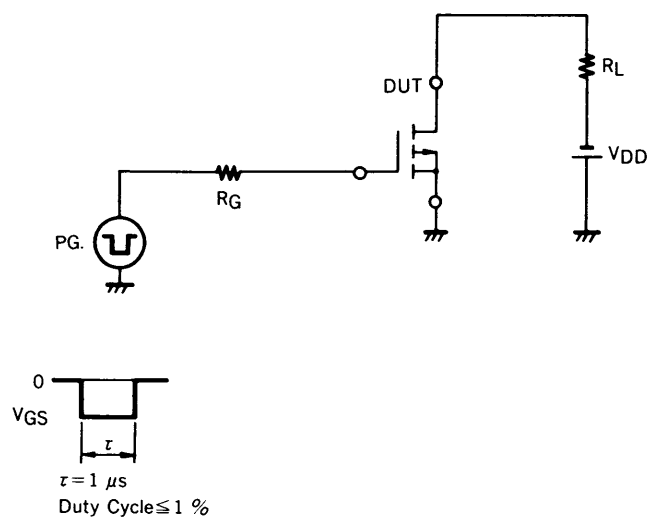


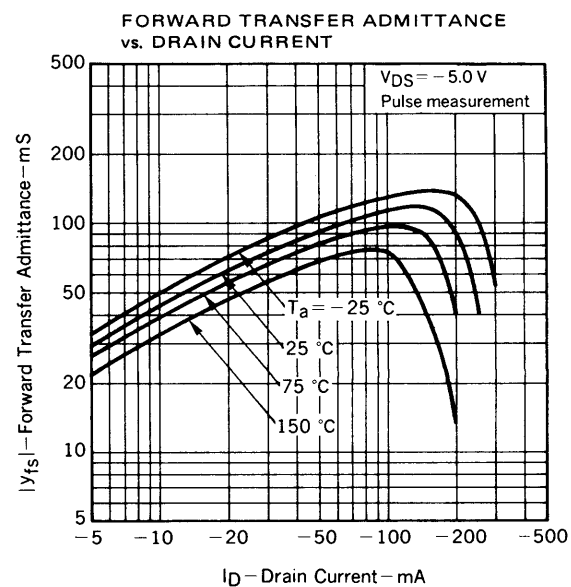
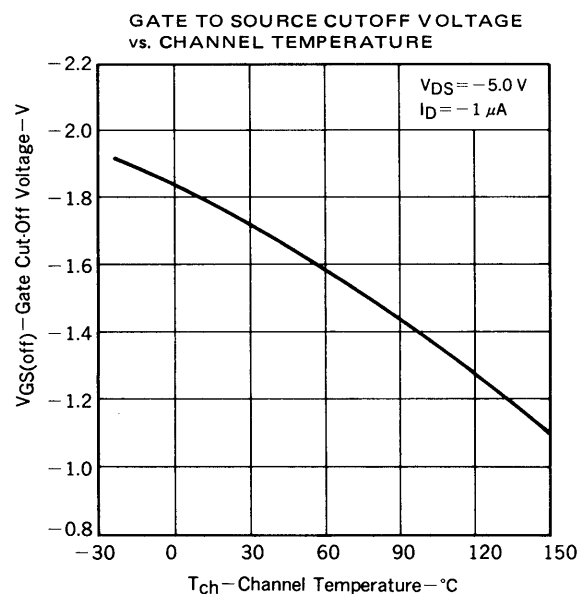
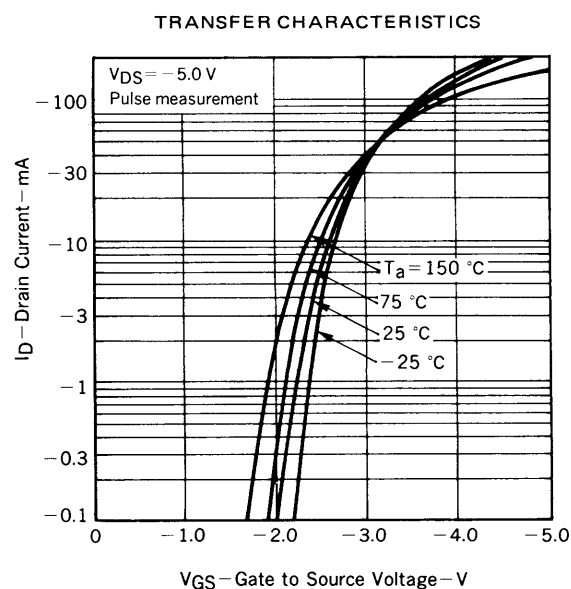
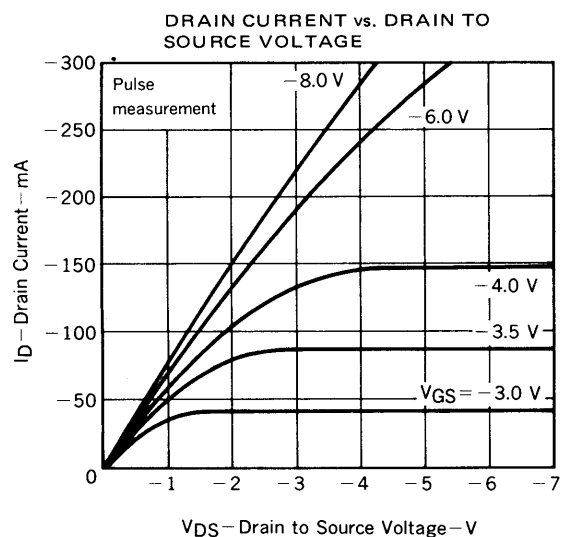
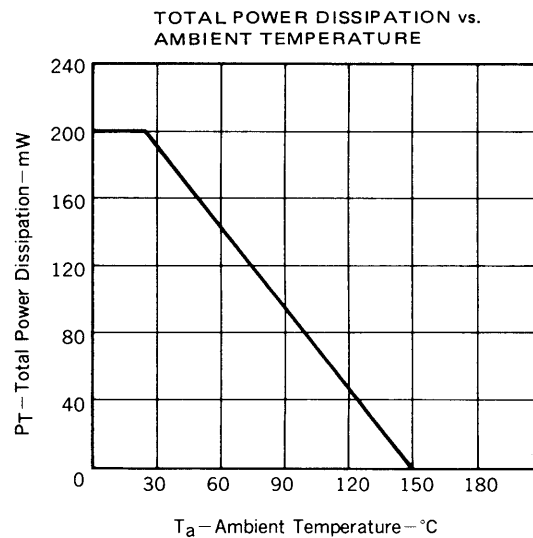
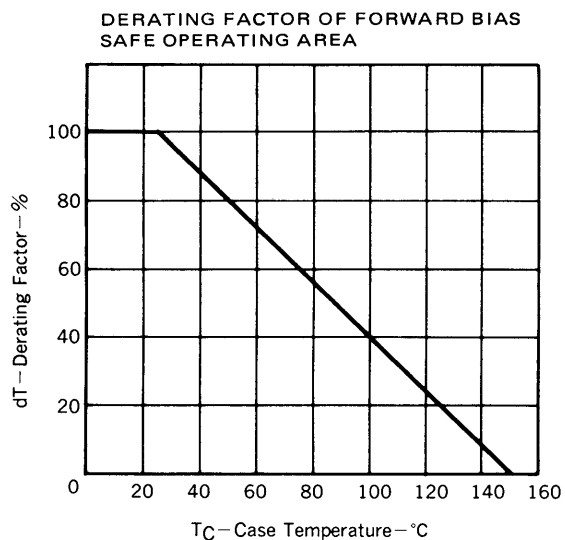
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V_{DSS}	−100	V	$V_{GS} = 0$
Gate to Source Voltage	V_{GSS}	±20	V	$V_{DS} = 0$
Drain Current	$I_D(DC)$	±200	mA	
Drain Current	$I_D(pulse)$	±400	μA	$PW \leq 10\text{ ms}$, Duty Cycle $\leq 50\%$
Total Power Dissipation	P_T	200	mW	
Channel Temperature	T_{ch}	150	°C	
Storage Temperature	T_{stg}	−55 to +150	°C	

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

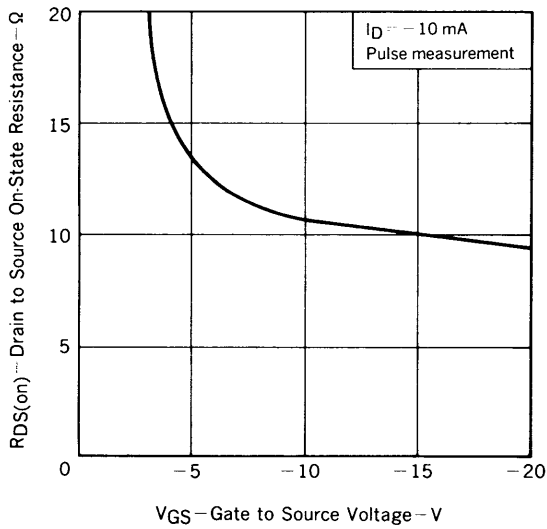
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	I_{DSS}			-1.0	μA	$V_{DS} = -100\text{ V}$, $V_{GS} = 0$
Gate Leakage Current	I_{GSS}			± 1.0	μA	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0$
Gate Cut-off Voltage	$V_{GS(off)}$	-1.4	-1.8	-2.4	V	$V_{DS} = -5.0\text{ V}$, $I_D = -1.0\text{ }\mu\text{A}$
Forward Transfer Admittance	$ y_{fs} $	20	45		mS	$V_{DS} = -5.0\text{ V}$, $I_D = -10\text{ mA}$
Drain to Source On-State Resistance	$R_{DS(on)1}$		15	30	Ω	$V_{GS} = -4.0\text{ V}$, $I_D = -10\text{ mA}$
Drain to Source On-State Resistance	$R_{DS(on)2}$		11	20	Ω	$V_{GS} = -10\text{ V}$, $I_D = -10\text{ mA}$
Input Capacitance	C_{iss}		27		pF	$V_{DS} = -5.0\text{ V}$, $V_{GS} = 0$, $f = 1\text{ MHz}$
Output Capacitance	C_{oss}		16		pF	
Feedback Capacitance	C_{rss}		2		pF	
Turn-On Delay Time	$t_{d(on)}$		110		ns	$V_{GS(on)} = -4\text{ V}$, $R_G = 10\text{ }\Omega$, $V_{DD} = -5\text{ V}$, $I_D = -10\text{ mA}$, $R_L = 500\text{ }\Omega$
Rise Time	t_r		150		ns	
Turn-Off Delay Time	$t_{d(off)}$		160		ns	
Fall Time	t_f		150		ns	

SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

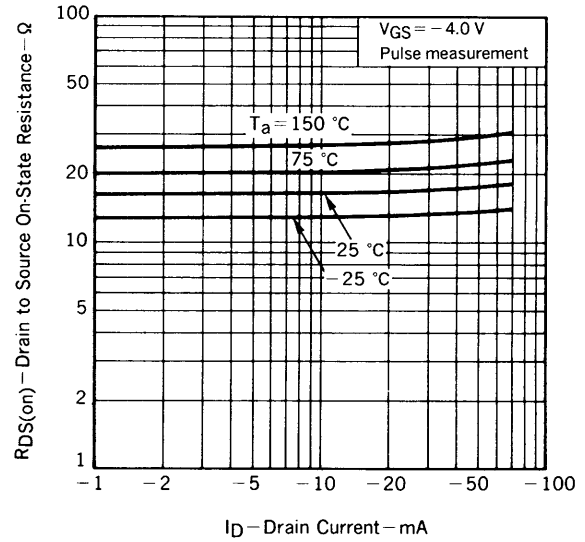


TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

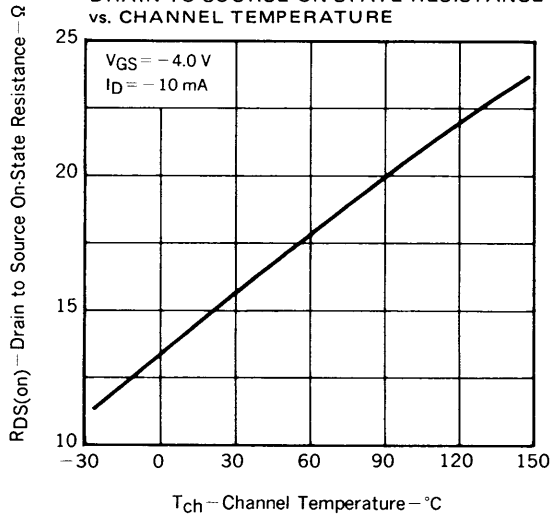
DRAIN TO SOURCE ON-STATE RESISTANCE
vs. GATE TO SOURCE VOLTAGE



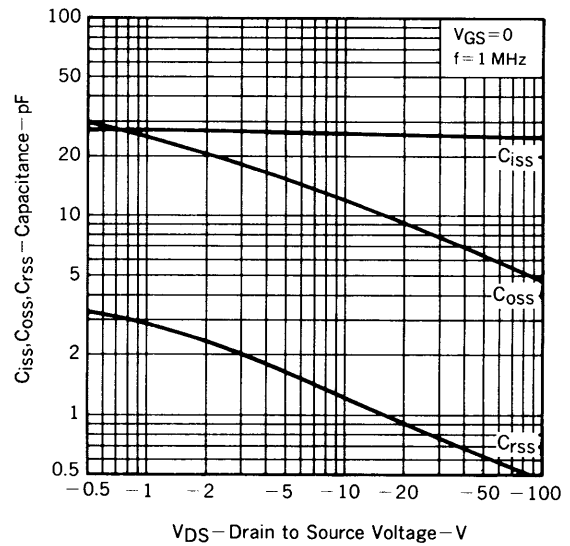
DRAIN TO SOURCE ON-STATE RESISTANCE
vs. DRAIN CURRENT



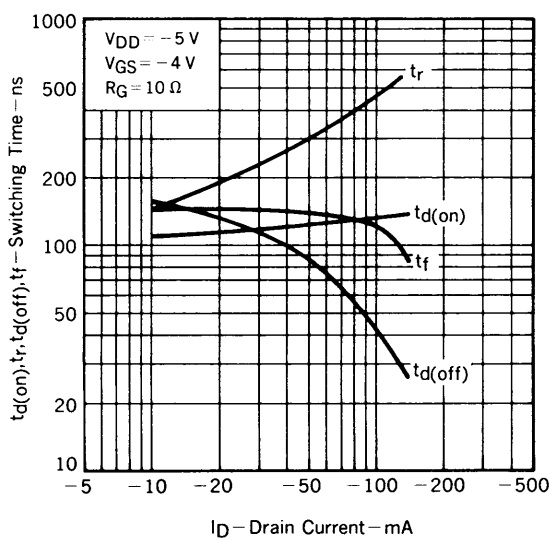
DRAIN TO SOURCE ON-STATE RESISTANCE
vs. CHANNEL TEMPERATURE



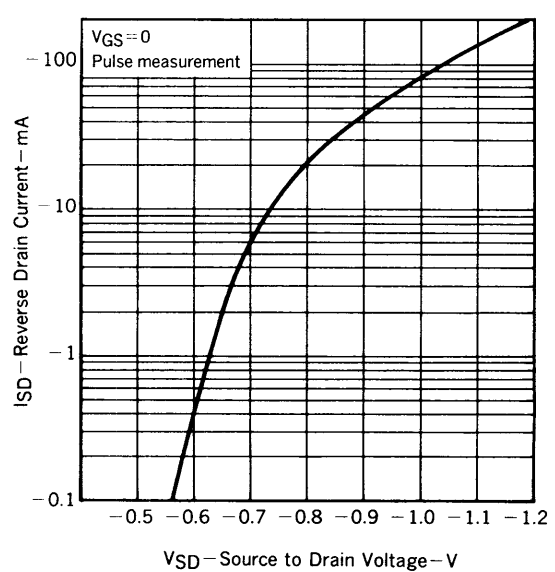
CAPACITANCE vs. DRAIN TO
SOURCE VOLTAGE



SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE
FORWARD VOLTAGE



RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.
Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document.
"Device Mounting Manual for Surface Mounting (IEI-616)."

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00

*: Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1: Combination of soldering methods should be avoided.

[MEMO]

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those intended to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime systems etc.